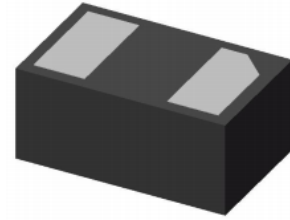


FEATURES:

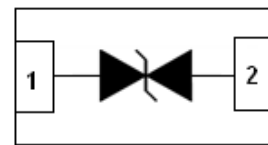
- ✧ Protects one bi-directional I/O line
- ✧ Low clamping voltage
- ✧ Low operating voltage: 5V
- ✧ ROHS compliant

MAIN APPLICATIONS

- ✧ Cell Phone Handsets and Accessories
- ✧ Personal Digital Assistants (PDA's)
- ✧ Notebooks, Desktops, and Servers
- ✧ Portable Instrumentation
- ✧ Pagers
- ✧ Microprocessor based equipment



DFN1006



PIN Configuration

PROTECTION SOLUTION TO MEET

- ✧ IEC61000-4-2 (ESD) ± 20 kV (air), ± 20 kV (contact)
- ✧ IEC61000-4-5 (Lighting) 4.0A (8/20us)

MECHANICAL CHARACTERISTICS

- ✧ Package DFN1006
- ✧ Molding Compound Flammability Rating : UL 94V-O
- ✧ Quantity Per Reel : 10,000pcs
- ✧ Lead Finish : Lead Free
- ✧ Marking code: 50

ABSOLUTE MAXIMUM RATINGS ($T_A=25^\circ\text{C}$, RH=45%-75%, unless otherwise noted)

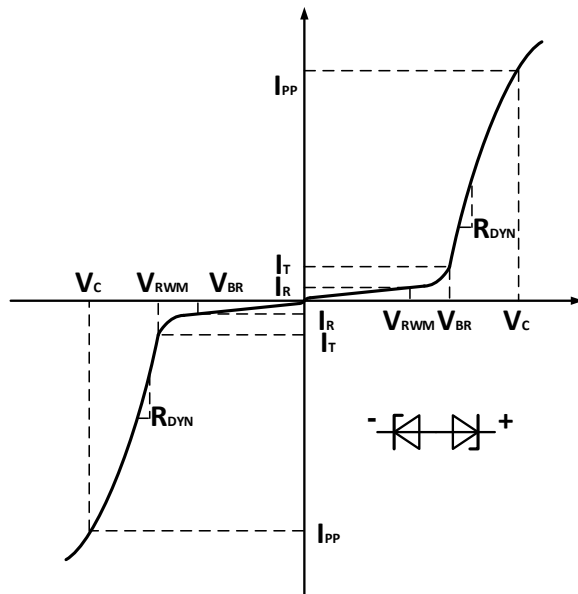
Parameter	Symbol	Value	Unit
Storage temperature range	T_{stg}	-55 to +150	$^\circ\text{C}$
Operating junction temperature range	T_j	-55 to +125	$^\circ\text{C}$
Lead Soldering Temperature	T_L	260 (10 sec.)	$^\circ\text{C}$
Peak pulse power dissipation on 8/20 μs waveform	P_{PP}	88	W
ESD per IEC 61000-4-2 (Air)	V_{ESD}	+/- 20	kV
ESD per IEC 61000-4-2 (Contact)		+/- 20	

ELECTRICAL CHARACTERISTICS (T_A=25°C)

Parameter	Symbol	Conditions	Min	Typ	Max	Units
Reverse Working Voltage	V _R				5	V
Reverse Breakdown Voltage	V _{BR}	I _T = 1mA	6.0			V
Reverse Leakage Current	I _R	V _R = 5V			1.0	μA
Peak Pulse Current	I _{pp}	t _p = 8/20μs			4.0	A
Clamping Voltage	V _C	I _{PP} = 1.0A, t _p = 8/20μs			13	V
		I _{PP} = 4.0A, t _p = 8/20μs			22	V
Junction Capacitance	C _J	V _R = 0V, f = 1MHz		0.22	0.35	pF

RATINGS AND V-I CHARACTERISTICS CURVES

Symbol	Parameter
V _{RWM}	Reverse Standoff Voltage
I _R	Max Reverse Leakage Current @ V _{RWM}
V _{BR}	Breakdown Voltage @ I _T
I _T	Test Current
V _C	Clamping Voltage @ I _{PP}
I _{PP}	Max Peak Pulse Current
R _{DYN}	Dynamic Resistance
C _J	Junction Capacitance
P _{PP}	Peak Pulse Power



RATINGS AND V-I CHARACTERISTICS CURVES ($T_A=25^\circ\text{C}$, unless otherwise noted)

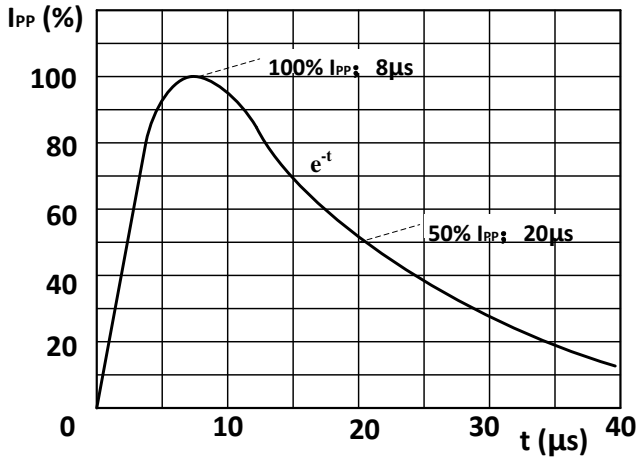


Fig. 1. 8/20 μs pulse waveform according to IEC 61000-4-5 and IEC 61643-321

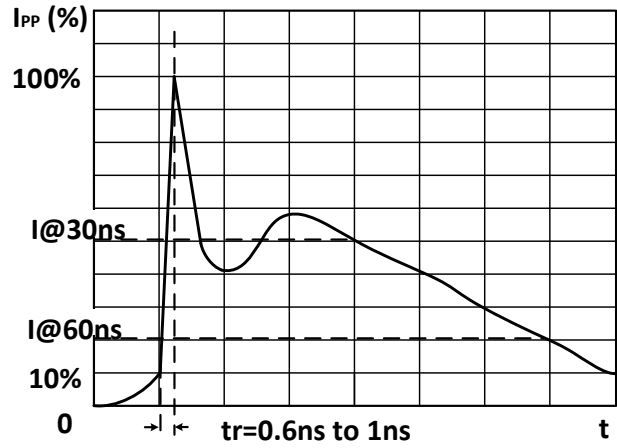


Fig. 2. ESD pulse waveform according to IEC 61000-4-2

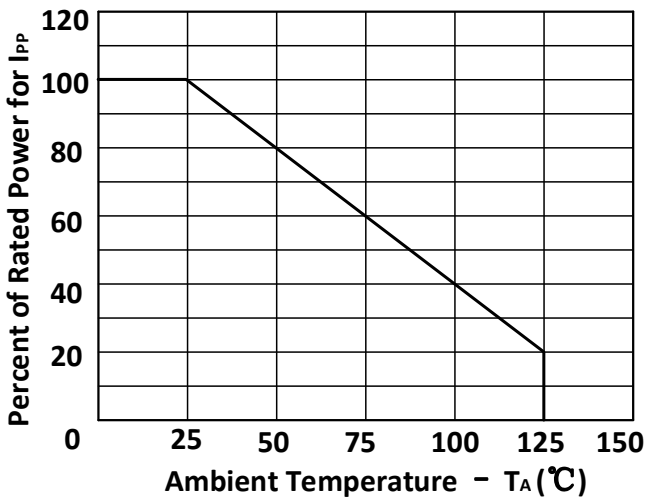


Fig. 3. Power Derating Curve

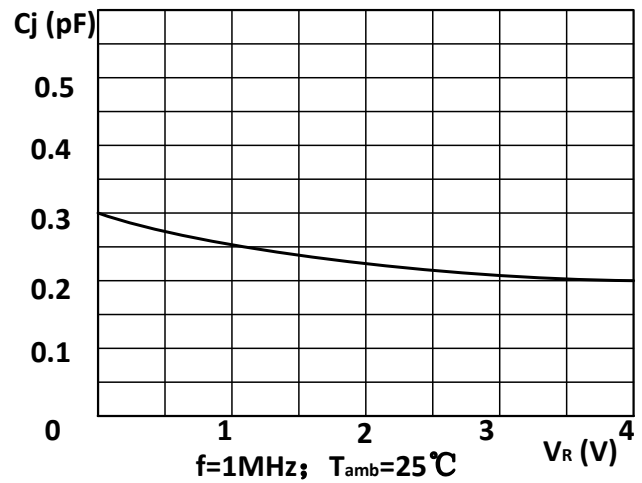
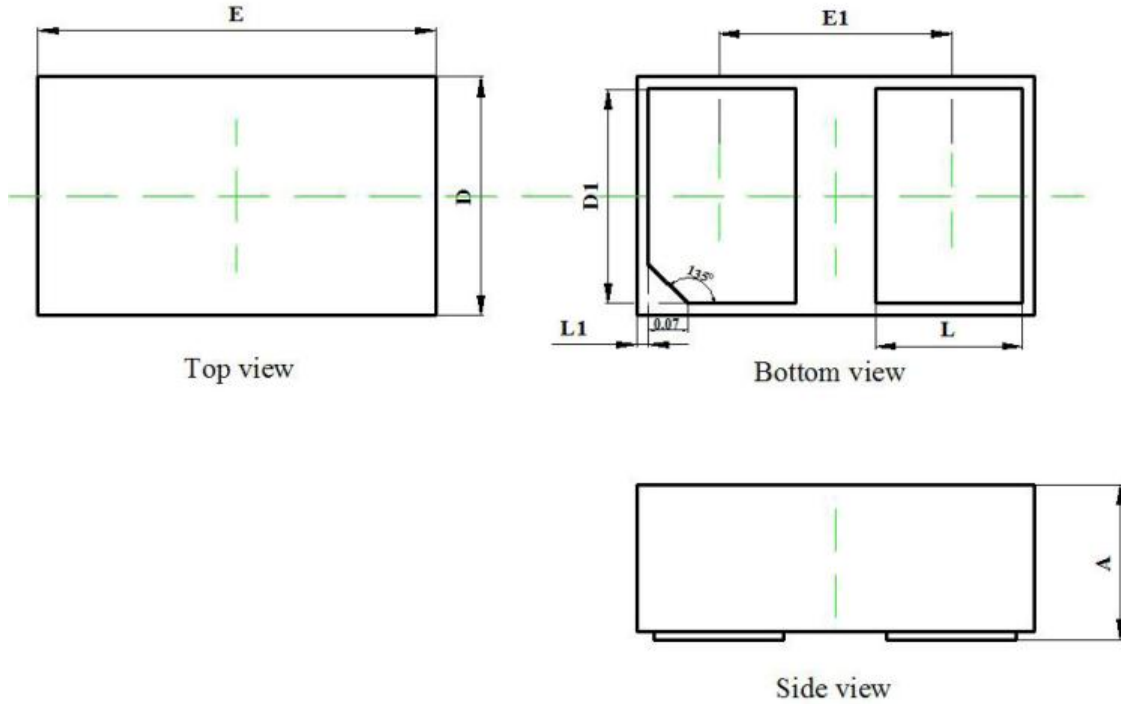


Fig. 4. Junction Capacitance vs V_R

PACKAGE MECHANICAL DATA



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	0.350	0.450	0.014	0.018
D	0.550	0.650	0.022	0.026
E	0.950	1.050	0.037	0.041
D1	0.420	0.520	0.017	0.020
E1	0.550	0.650	0.022	0.026
L	0.270	0.370	0.011	0.015
L1	0.000	0.100	0.000	0.004

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